Dielectric characteristics





Multilayer Ceramic Capacitors are generally divided into classes which are defined by the capacitance temperature characteristics over specified temperature ranges. These are designated by alpha numeric codes. Code definitions are summarised below and are also available in the relevant national and international specifications.

Capacitors within this class have a dielectric constant range from 10 to 100. They are used in applications which require ultra stable

dielectric characteristics with negligible dependence of capacitance and dissipation factor with time, voltage and frequency. They exhibit the following characteristics:-

- a) Time does not significantly affect capacitance and dissipation factor (Tan δ) no ageing.
- b) Capacitance and dissipation factor are not affected by voltage.
- c) Linear temperature coefficient.

		Class I Dielectrics								
		COG/NPO (Porcelain)	P90 (Porcelain)	COG/NPO		X8G	Class I High Temperature			
Dielectric classifications		Ultra stable	Ultra stable	Ultra stable		Ultra stable	Ultra stable			
	IECQ-CECC	-	-	1B/CG		-	-	-		
	EIA	C0G/NP0	P90	COG/NP0		X8G	-	-		
	MIL	-	-	CG (BP)		-	-	-		
Ordering code	DLI	CF	АН	-	-	-	-	-		
	Novacap	-	-	-	N	-	F	D, RD		
	Syfer	-	-	Q, U	С	Н	-	G		
	Voltronics	F	Н	Q	-	-	-	-		
Rated temperature range		-55°C to +125°C	-55°C to +125°C	-55°C to +125°C	-55°C to +125°C	-55°C to +150°C	-55°C to +160°C	-55°C to +200°C		
Maximum capacitance change over temperature range	No DC voltage applied	0 ± 15 ppm/°C	± 20 ppm/°C	0 ± 30 ppm/°C	± 30 ppm/°C	0 ± 30 ppm/°C	0 ± 30 ppm/°C	0 ± 30 ppm/°C		
	Rated DC voltage applied	-								
Tangent of loss angle (tan δ)		≤0	.05	≤0.0005 @1MHz	$>50pF \le 0.0015$ $\le 50pF 0.0015 (15 + 0.7)$ Cr		≤0.001			
Insulation resistance (Ri)	Time constant (Ri x Cr)	@25°C = 1 @125°C =		$100G\Omega$ or $1000s$ (whichever is the least)			@25°C = 100 GΩ or 100 0ΩF @ 160 °C & 200 °C = 1 GΩ or 10 ΩF (whichever is the least)			
	Cr <4.7pF	±0.05pF, ±0.10pF, ±0.25pF, ±0.5pF								
Capacitance Tolerance	Cr ≥4.7 to <10pF	±0.10pF, ±0.25pF, ±0.5pF								
	Cr ≥10pF	±1%, ±2%, ±5%, ±10%								
Distribute	<u><</u> 200V		2.5 times	2.5 times		2.5 times	2.5 times			
Dielectric strength Voltage applied	>200V to <500V	2.5 times		Rated voltage + 250V			Rated voltage + 250V			
for 5 seconds. Charging	500V to <u><</u> 1kV			1.5 times			1.5 times			
current limited to 50mA maximum.	>1kV to ≤1.2kV		N/A	1.25 times			1.25 times			
	>1.2kV			1.2 times			1.2 times			
Climatic category (IEC)	Chip	55/125/56	55/125/56	55/12	25/56	-	-			
	Dipped	-	-	-	55/125/21	-	-			
	Discoidal	-	-	-	55/125/56	-	-			
Ageing characteristic (Typical)		Zero								
Approvals	Syfer Chip	-	-	-	QC-32100	-		-		

Dielectric characteristics

Class II Dielectrics

Capacitors of this type have a dielectric constant range of 1000-4000 and also have a non-linear temperature characteristic which exhibits a dielectric constant variation of less than $\pm 15\%$ (2R1) from its room temperature value, over the specified temperature range. Generally used for by-passing (decoupling), coupling, filtering, frequency discrimination, DC blocking and voltage transient suppression with greater volumetric efficiency than Class I units, whilst maintaining stability within defined limits.

Capacitance and dissipation factor are affected by:-

- a) Time (Ageing)
- b) Voltage (AC or DC)
- c) Frequency

X5R	X7R			X8R	Class II High Temperature					
Stable	Stable			Stable	Stable					
-	2C1	2R1	2X1	-	-	-	IECQ-CECC	Dielectric		
X5R	-	X7R	-	X8R	-	-	EIA	classifications		
-	BZ	-	BX	-	-	-	MIL			
-	-	-	-	-	-	-	DLI	Ordering code		
BW	-	В	X	S	G	E, RE	Novacap			
Р	R	X	В	N	-	Χ	Syfer	Ordering code		
-	-	X	-	-	-	-	Voltronics			
-55°C to +85°C	-55°C to +125°C			-55°C to +150°C	-55°C to +160°C	-55°C to +200°C		Rated temperature range		
±15%	±15%	±15%	±15%	±15%	+15 -40%	+15 -65%	No DC voltage applied	Maximum capacitance		
-	+15 -45%	-	+15 -25%	-	-	-	Rated DC voltage applied	change over temperature range		
≤ 0.025 Typical*		>25V <0.025 <25V <0.035		≤0.025	<u>≤</u> 0.	025		Tangent of loss angle (tan δ)		
	Time constant (Ri x Cr)	Insulation resistance (Ri)								
		Capacitance Tolerance								
	2.5 times			2.5 times	2.5 times		<u>≤</u> 200V	Dielectric strength Voltage applied for 5 seconds. Charging current limited to 50mA maximum.		
2.5 times	Rated voltage + 250V				Rated voltage + 250V		>200V to <500V			
	1.5 times				1.5 times		500V to <1kV			
	1.2 times				1.2 times		≥1kV			
55/85/56	55/125/56			55/150/56	-		Chip	Climatic		
-	55/125/21			-	-		Dipped	Climatic category (IEC)		
-	55/125/56						Discoidal			
5% Typical	<2% per time decade							Ageing characteristic (Typical)		
-	QC-32100	-	-	-	QC-32100	-	Syfer Chip	Approvals		

 $[\]ensuremath{^{*}}$ Refer to page 34 for details of Dissipation Factor.